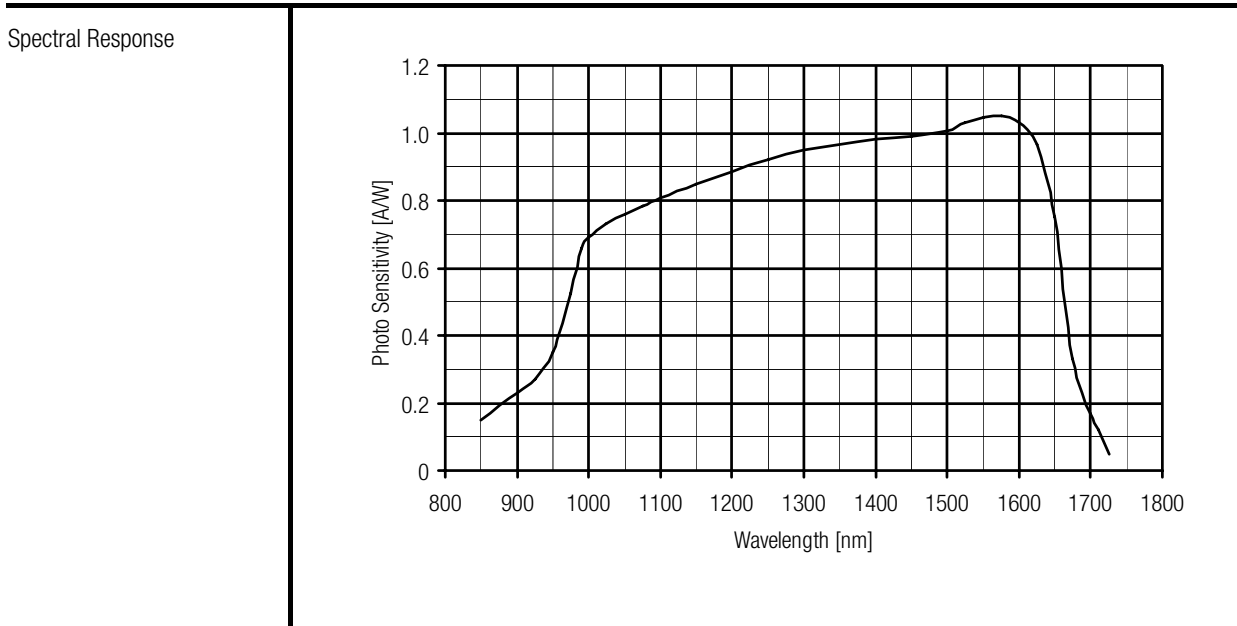


400 MHz Photoreceiver with InGaAs PIN Photodiode

Features	<ul style="list-style-type: none"> • InGaAs PIN Detector, 0.1 mm Active Diameter in FC Receptacle • Spectral Range 900 ... 1700 nm • Bandwidth DC ... 400 MHz • Amplifier Transimpedance (Gain) 5.0×10^3 V/A • Max. Conversion Gain 5.0×10^3 V/W (@ 1550 nm) 																																
Applications	<ul style="list-style-type: none"> • Spectroscopy • Fast Pulse and Transient Measurements • Optical Triggering • Optical Front-End for Oscilloscopes and A/D Converters 																																
Specifications	<p><i>Test Conditions</i> <i>V_s = ± 15 V, T_a = 25°C</i></p> <table border="0" style="width: 100%;"> <tr> <td style="width: 20%;">Gain</td> <td style="width: 40%;">Transimpedance</td> <td style="width: 40%;">5.0 x 10³ V/A (@ 50 Ω load)</td> </tr> <tr> <td></td> <td>Max. Conversion Gain</td> <td>5.0 x 10³ V/W (@ 1550 nm)</td> </tr> <tr> <td rowspan="4">Frequency Response</td> <td>Lower Cut-Off Frequency</td> <td>DC</td> </tr> <tr> <td>Upper Cut-Off Frequency (- 3 dB)</td> <td>400 MHz (± 10%)</td> </tr> <tr> <td>Rise/Fall Time (10% - 90%)</td> <td>1.0 ns</td> </tr> <tr> <td>Gain Flatness</td> <td>± 1 dB</td> </tr> <tr> <td rowspan="3">Detector</td> <td>Detector Material</td> <td>InGaAs PIN photodiode</td> </tr> <tr> <td>Active Area</td> <td>Ø 0.1 mm in FC receptacle</td> </tr> <tr> <td>Spectral Response</td> <td>900 ... 1700 nm</td> </tr> <tr> <td rowspan="3">Input</td> <td>Input Offset Compensation</td> <td>± 200 µA adjustable by offset trimpot</td> </tr> <tr> <td>Max. Optical Input Power</td> <td>200 µW (for linear amplification, @ 1550 nm)</td> </tr> <tr> <td>Min. NEP</td> <td>21 pW/√Hz (@ 1550 nm, 100 MHz)</td> </tr> </table>		Gain	Transimpedance	5.0 x 10 ³ V/A (@ 50 Ω load)		Max. Conversion Gain	5.0 x 10 ³ V/W (@ 1550 nm)	Frequency Response	Lower Cut-Off Frequency	DC	Upper Cut-Off Frequency (- 3 dB)	400 MHz (± 10%)	Rise/Fall Time (10% - 90%)	1.0 ns	Gain Flatness	± 1 dB	Detector	Detector Material	InGaAs PIN photodiode	Active Area	Ø 0.1 mm in FC receptacle	Spectral Response	900 ... 1700 nm	Input	Input Offset Compensation	± 200 µA adjustable by offset trimpot	Max. Optical Input Power	200 µW (for linear amplification, @ 1550 nm)	Min. NEP	21 pW/√Hz (@ 1550 nm, 100 MHz)		
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400 MHz Photoreceiver with InGaAs PIN Photodiode

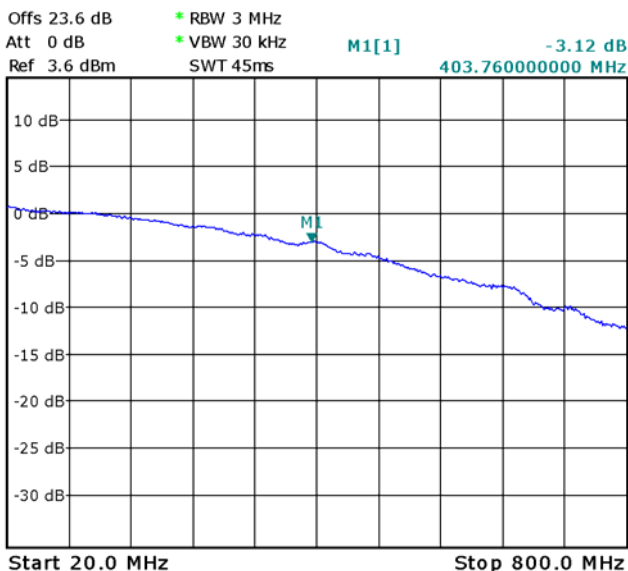


Connectors	<p>Input: optical, FC receptacle</p> <p>Output: BNC</p> <p>Power Supply: LEMO series 1S, 3-pin fixed socket</p> <p>Pin 1: + 15V</p> <p>Pin 2: - 15V</p> <p>Pin 3: GND</p>
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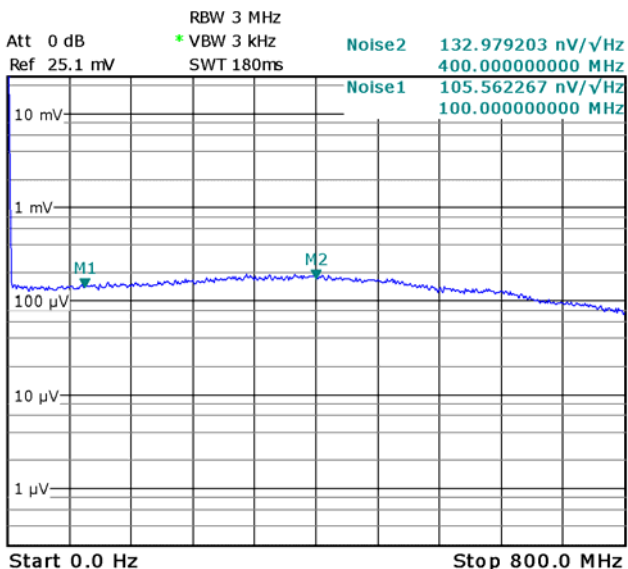
400 MHz Photoreceiver with InGaAs PIN Photodiode

Typical Performance Characteristics

Frequency Response



Noise Spectrum



Note: Spectral noise data is measured at the amplifier output with darkened photo diode. To determine the spectral input noise divide the measured output noise by the amplifier conversion gain.

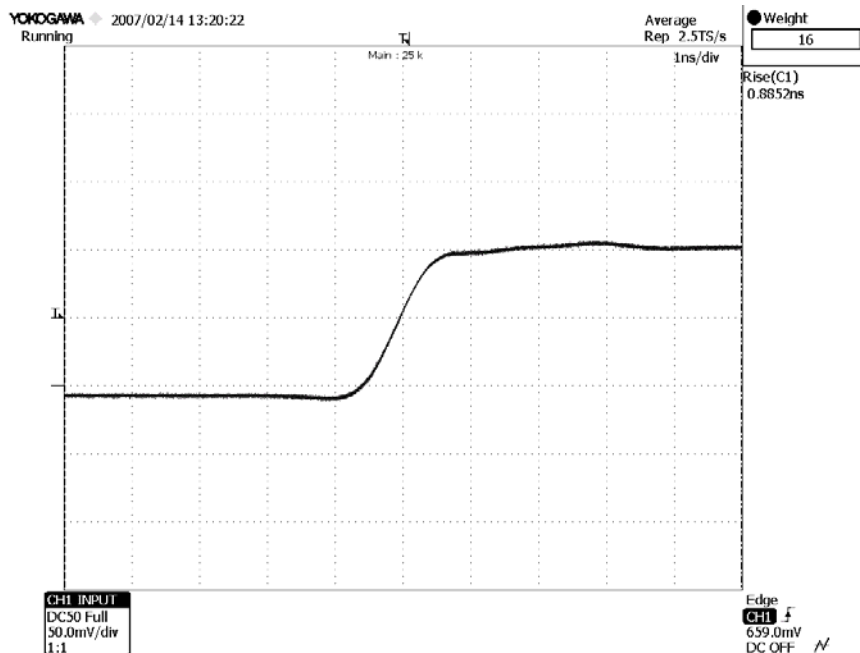
Conversion gain (V/W) = amplifier gain (5,000 V/A) x photo sensitivity (A/W).

Marker	Frequency	Output Noise	Resulting Input Noise (NEP)
1	100 MHz	106 nV/√Hz	21 pW/√Hz (@ 1550 nm)
2	400 MHz	133 nV/√Hz	27 pW/√Hz (@ 1550 nm)

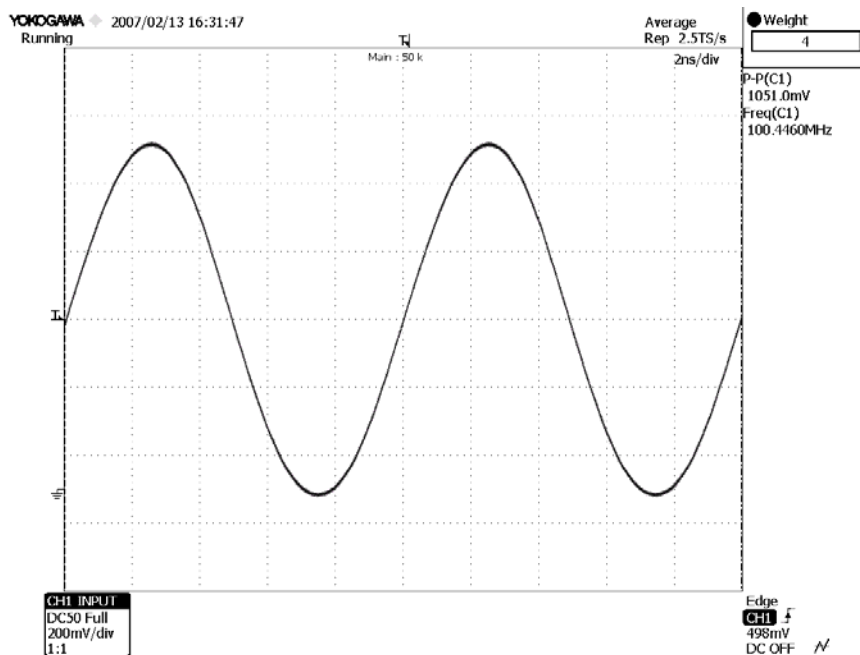
400 MHz Photoreceiver with InGaAs PIN Photodiode

Typical Performance Characteristics (continued)

Pulse Response to Square Wave Input Signal (with 16 times averaging)



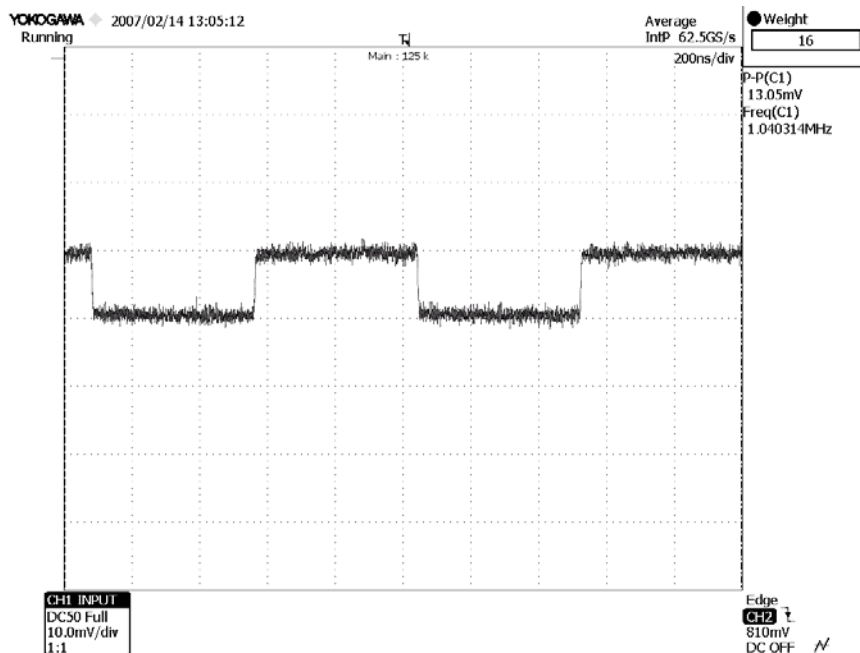
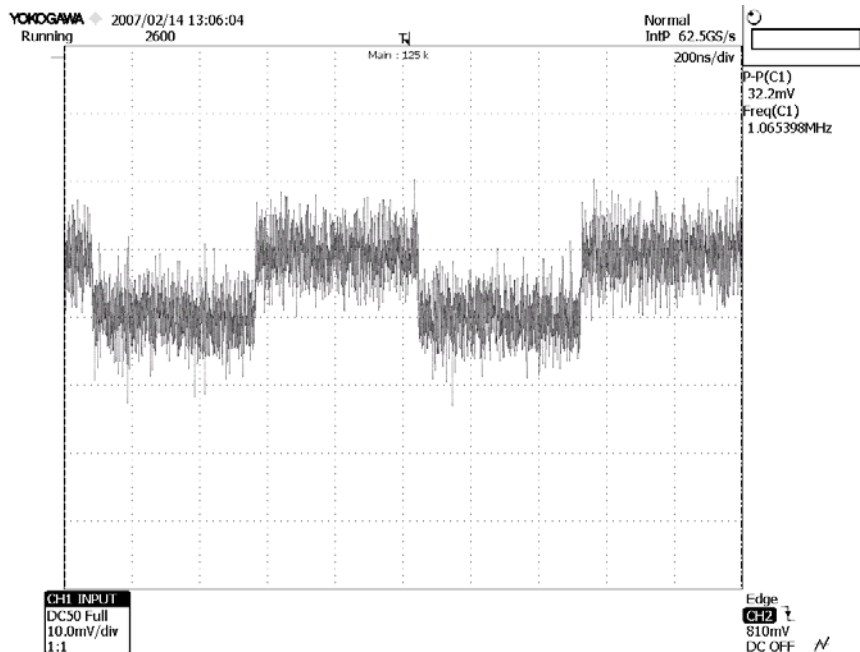
Large Signal Response output signal for 100 MHz, 200 μ W modulated optical input signal (with 4 times averaging)



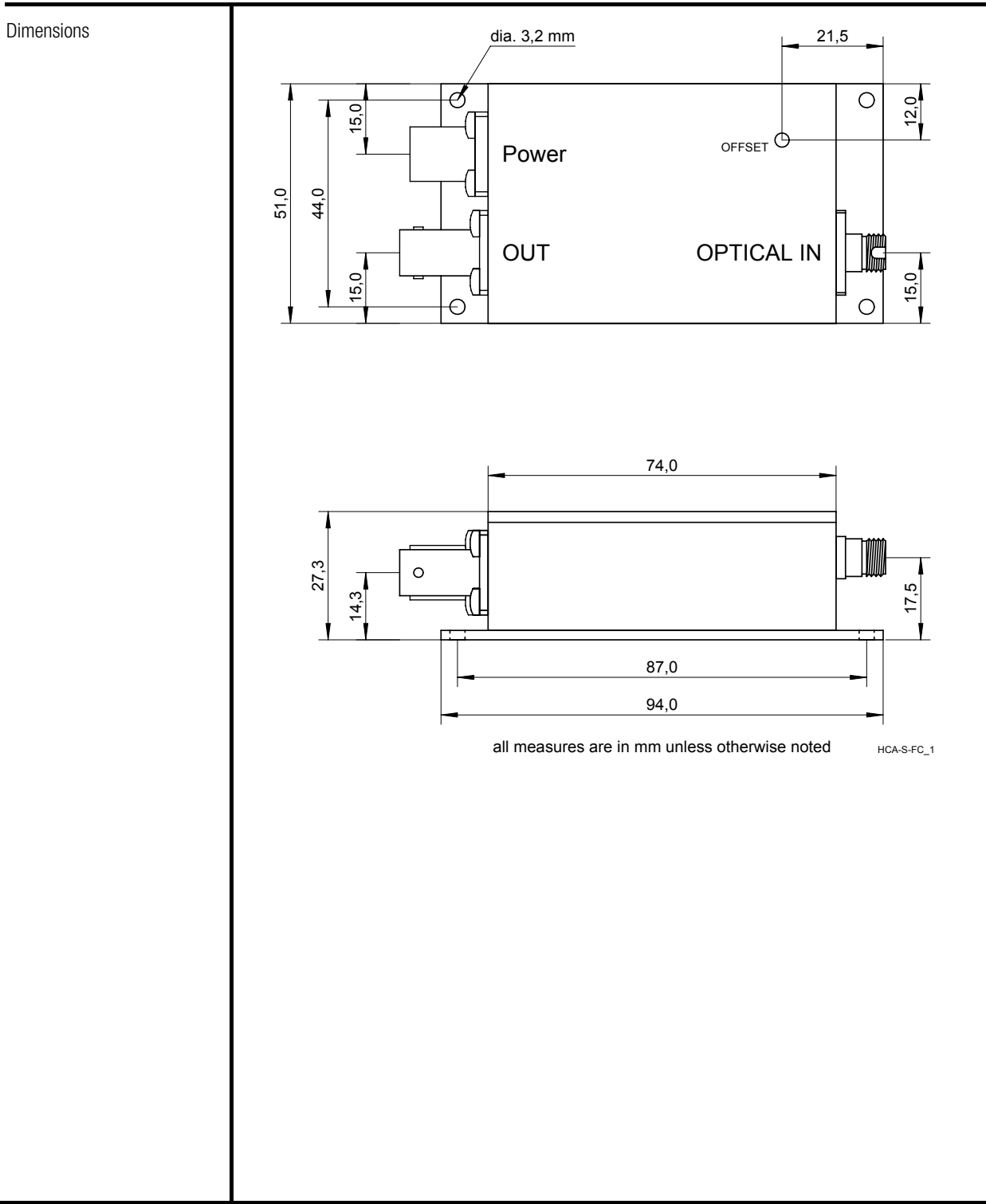
400 MHz Photoreceiver with InGaAs PIN Photodiode

Typical Performance Characteristics (continued)

Small Signal Response
output signal for 2 μ W modulated optical input signal, 1 MHz square wave (without (top) and with 64 times averaging (bottom))



400 MHz Photoreceiver with InGaAs PIN Photodiode



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